

NPN SILICON PLANAR TRANSISTOR

2N3019 / 2N3020



TO-39
Metal Can Package

General Transistor

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Emitter Voltage	V_{CEO}	80	V
Collector Base Voltage	V_{CBO}	140	V
Emitter Base Voltage	V_{EBO}	7.0	V
Collector Current Continuous	I_C	1.0	A
Power Dissipation at $T_a=25^\circ\text{C}$ Derate Above 25°C	P_D	0.8 4.6	W mW/ $^\circ\text{C}$
Power Dissipation at $T_c=25^\circ\text{C}$ Derate Above 25°C	P_D	5.0 28.6	W mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_j, T_{stg}	- 65 to +200	$^\circ\text{C}$

THERMAL RESISTANCE

Junction to Case	$R_{th(j-c)}$	16.5	$^\circ\text{C/W}$
Junction to Ambient in free air	$R_{th(j-a)}$	89.5	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

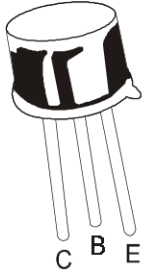
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Voltage	V_{CEO}	$I_C=1\text{mA}, I_B=0$	80			V
Collector Base Voltage	V_{CBO}	$I_C=100\mu\text{A}, I_E=0$	140			V
Emitter Base Voltage	V_{EBO}	$I_E=100\mu\text{A}, I_C=0$	7.0			V
Collector Cut Off Current	I_{CBO}	$V_{CB}=90\text{V}, I_E=0$			10	nA
		$V_{CB}=90\text{V}, I_E=0, T_a=150^\circ\text{C}$			10	μA
Emitter Cut Off Current	I_{EBO}	$V_{EB}=5\text{V}, I_C=0$			10	nA
DC Current Gain	h_{FE}	$I_C=0.1\text{mA}, V_{CE}=10\text{V}$	>50		30 - 100	
		$I_C=10\text{mA}, V_{CE}=10\text{V}$	>90		40 - 120	
		$I_C=150\text{mA}, V_{CE}=10\text{V}$	100 - 300		40 - 120	
		$I_C=150\text{mA}, V_{CE}=10\text{V}, T_c=-55^\circ\text{C}$	>40		-	
		$I_C=500\text{mA}, V_{CE}=10\text{V}$	>50		30 - 100	
		$I_C=1\text{A}, V_{CE}=10\text{V}$	>15		>1	
			MIN	TYP	MAX	UNIT
Collector Emitter Saturation Voltage	$*V_{CE(sat)}$	$I_C=150\text{mA}, I_B=15\text{mA}$			0.2	V
		$I_C=500\text{mA}, I_B=50\text{mA}$			0.5	V
Base Emitter Saturation Voltage	$*V_{BE(sat)}$	$I_C=150\text{mA}, I_B=15\text{mA}$			1.1	V

*Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 1\%$

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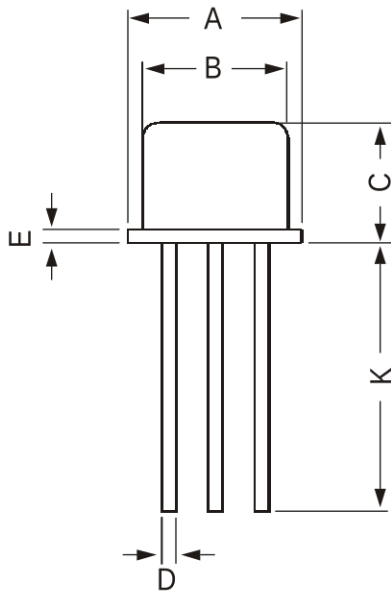
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless specified otherwise)

SMALL SIGNAL CHARACTERISTICS

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$			12	pF
Input Capacitance	C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=1\text{MHz}$			60	pF
Small Signal Current Gain	h_{fe}	$I_C=1\text{mA}, V_{CE}=5\text{V}, f=1\text{KHz}$ 2N3019 2N3020	80 30		400 200	
Collector Base Time Constant	$r_b'C_C$	$I_E=10\text{mA}, V_{CB}=10\text{V}, f=79.8\text{MHz}$			400	ps
Noise Figure	NF	$I_C=100\mu\text{A}, V_{CE}=10\text{V}, R_S=1\text{K}\Omega,$ $f=1.0\text{KHz}$ 2N3019			4.0	dB

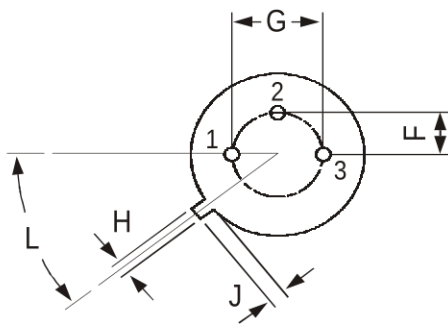
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TO-39 Metal Can Package



All dimensions are in mm

DIM	MIN	MAX
A	8.50	9.39
B	7.74	8.50
C	6.09	6.60
D	0.40	0.53
E	—	0.88
F	2.41	2.66
G	4.82	5.33
H	0.71	0.86
J	0.73	1.02
K	12.70	—
L	42 DEG	48 DEG



PIN CONFIGURATION

1. EMITTER
2. BASE
3. COLLECTOR

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20K	17" x 15" x 13.5"	32K	40 kgs

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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